NSN 5961-01-595-5644

Transistor - Page 1 of 1

Fiig: A110a0



View Online at https://aerobasegroup.com/nsn/5961-01-595-5644 **Inclosure Material:** Plastic **Overall Length:** 10.42 millimeters **Overall Height:** 2.38 millimeters **Overall Width:** 6.60 millimeters **Mounting Method: Terminal Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 100.0 breakdown voltage, drain-to-source, with all other terminals short-circuited to source **Current Rating Per Characteristic:** 1.60 amperes drain current **Power Rating Per Characteristic:** 79.0 watts total device dissipation **Maximum Operating Tempurature Per Measurement Point:** 175.0 degrees celsius junction **Product Name:** 100v single n channel hexfet power mosfet in a d-pak package **Terminal Type And Quantity:** 3 insulated wire lead Shelf Life: N/a **Unit Of Measure:** Demilitarization: No